

View Online at <https://aerobasegroup.com/nsn/5961-01-598-9426>

Mounting Facility Quantity:

1

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon alloy

Voltage Rating In Volts Per Characteristic:

400.0 repetitive peak reverse voltage and 600.0 repetitive peak reverse voltage and 400.0 working peak reverse voltage and 600.0 working peak reverse voltage

Product Name:

Hyperfast diode

Special Features:

This diode is of silicon nitride passivated ion-implanted epitaxial planar construction and takes 8 amps.

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fig:

A110a0